



# Multiscale 3-D X-ray Imaging for 3-D IC Process Development and Failure Analysis

W. Yun, M. Feser, J. Gelb, L. Hunter

# Xradia Inc.

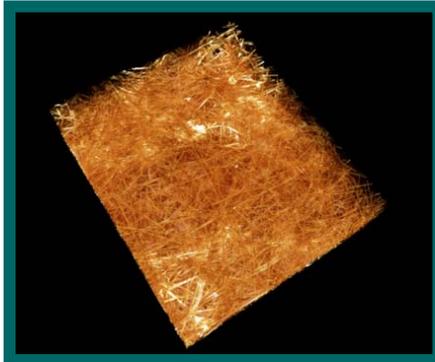
*Pioneer in Ultra-high Resolution 3D X-ray Microscopy*

- ▣ Founded in 2000 by Wenbing Yun to commercialize high resolution x-ray imaging from synchrotron sources to the laboratory
- ▣ HQ in Pleasanton, CA
- ▣ Core competencies: x-ray optics/imaging, detectors, system architecture
- ▣ Comprehensive market focus
  - From Synchrotron – large installed base of synchrotron 3D microscopes
  - To Research and Industry Labs – Highest performance X-ray microscopes for:

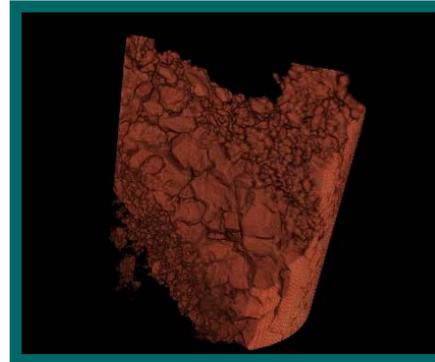
**Electronics**



**Materials Science**



**Geosciences**



**Life Sciences**

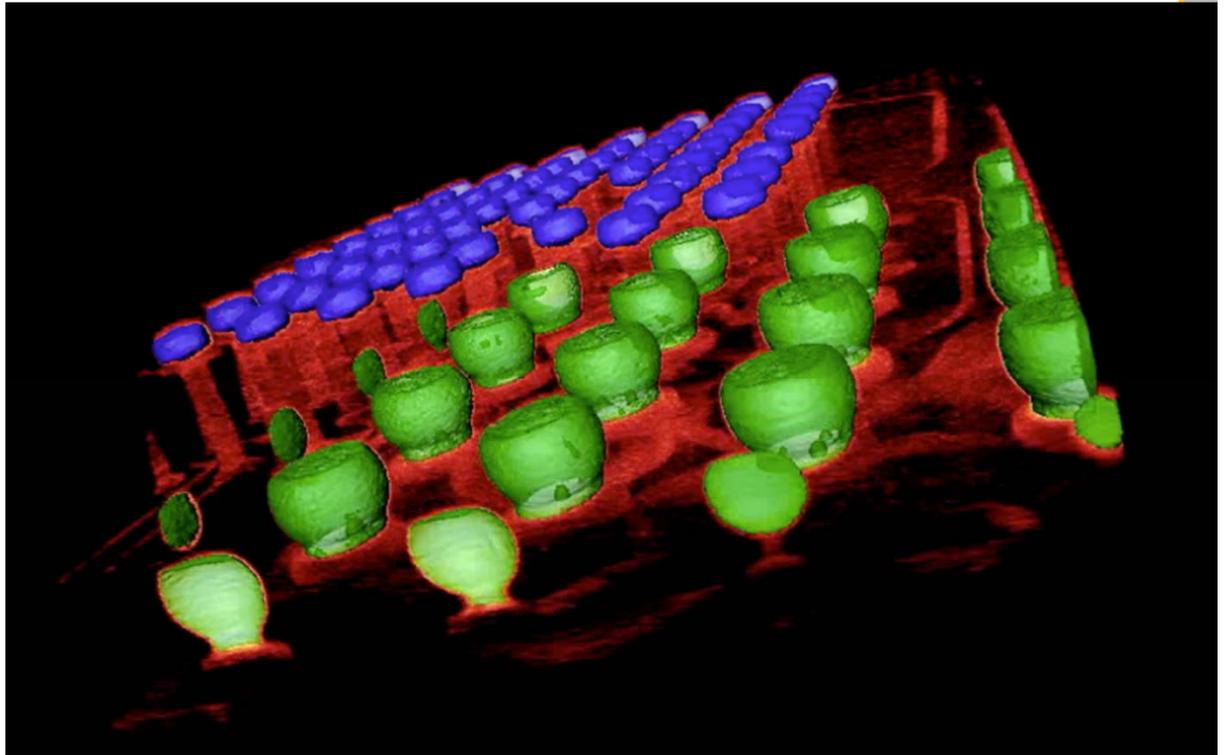


# 3D X-Ray Microscopy (XRM)

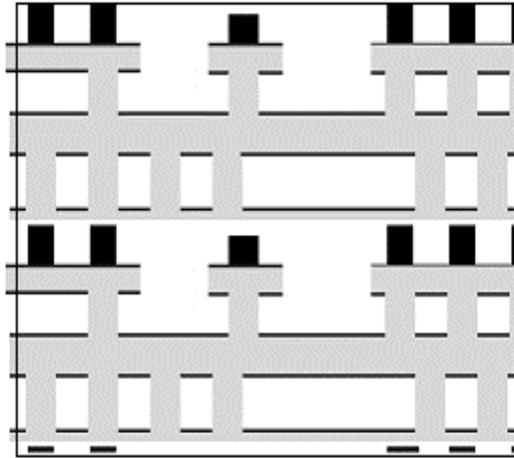
Fully packaged IC  
Sample



3D XRM Data Set

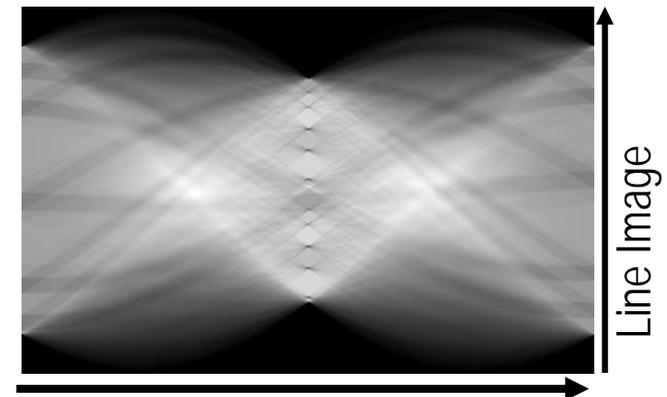


# Computed Tomography



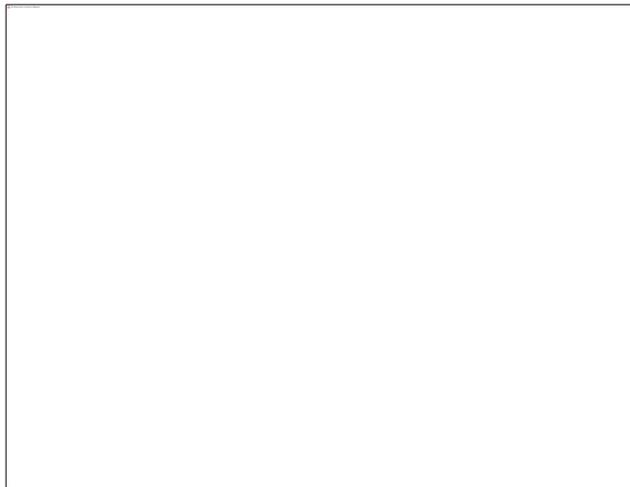
(1) Sample imaged at various angles to acquire tomographic projections.

Sinogram



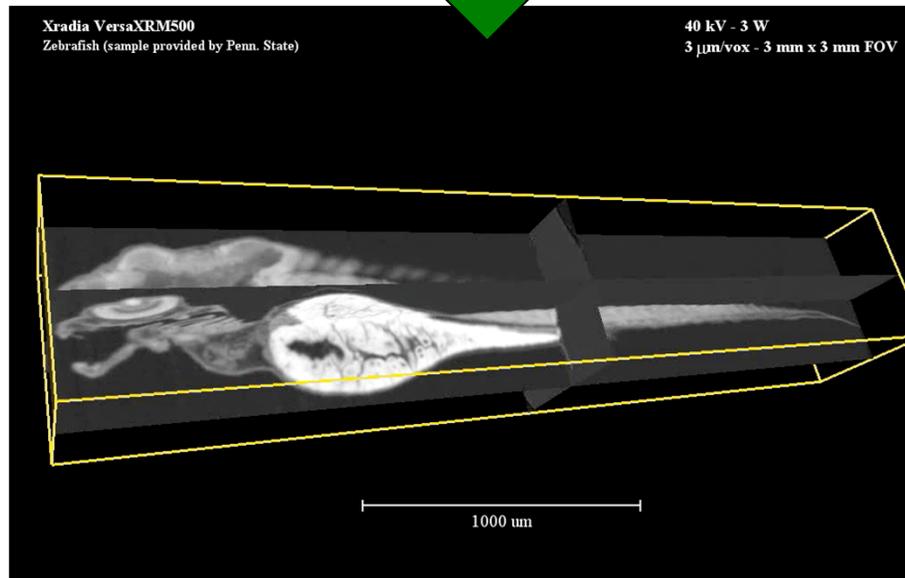
Sample rotation angle

(2) 3D reconstruction by backprojection results in 3D image of the sample.

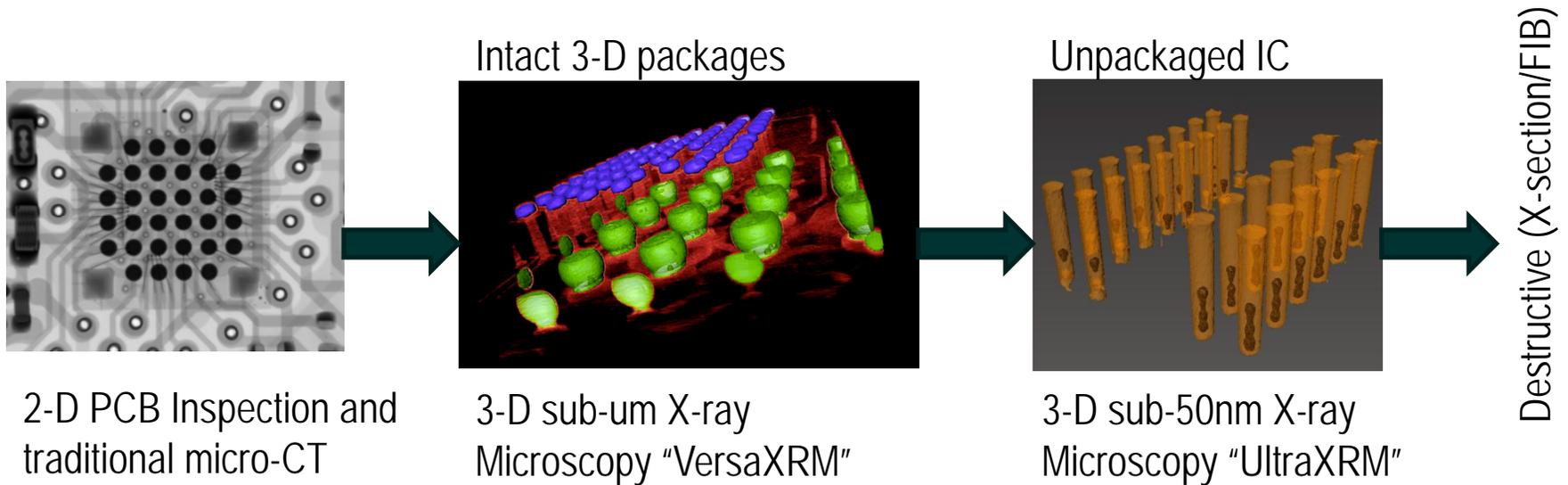


# What Can You Do With a 3D XRM Dataset?

**Non-  
Destructive**  
**Virtual  
Cross  
Sections**

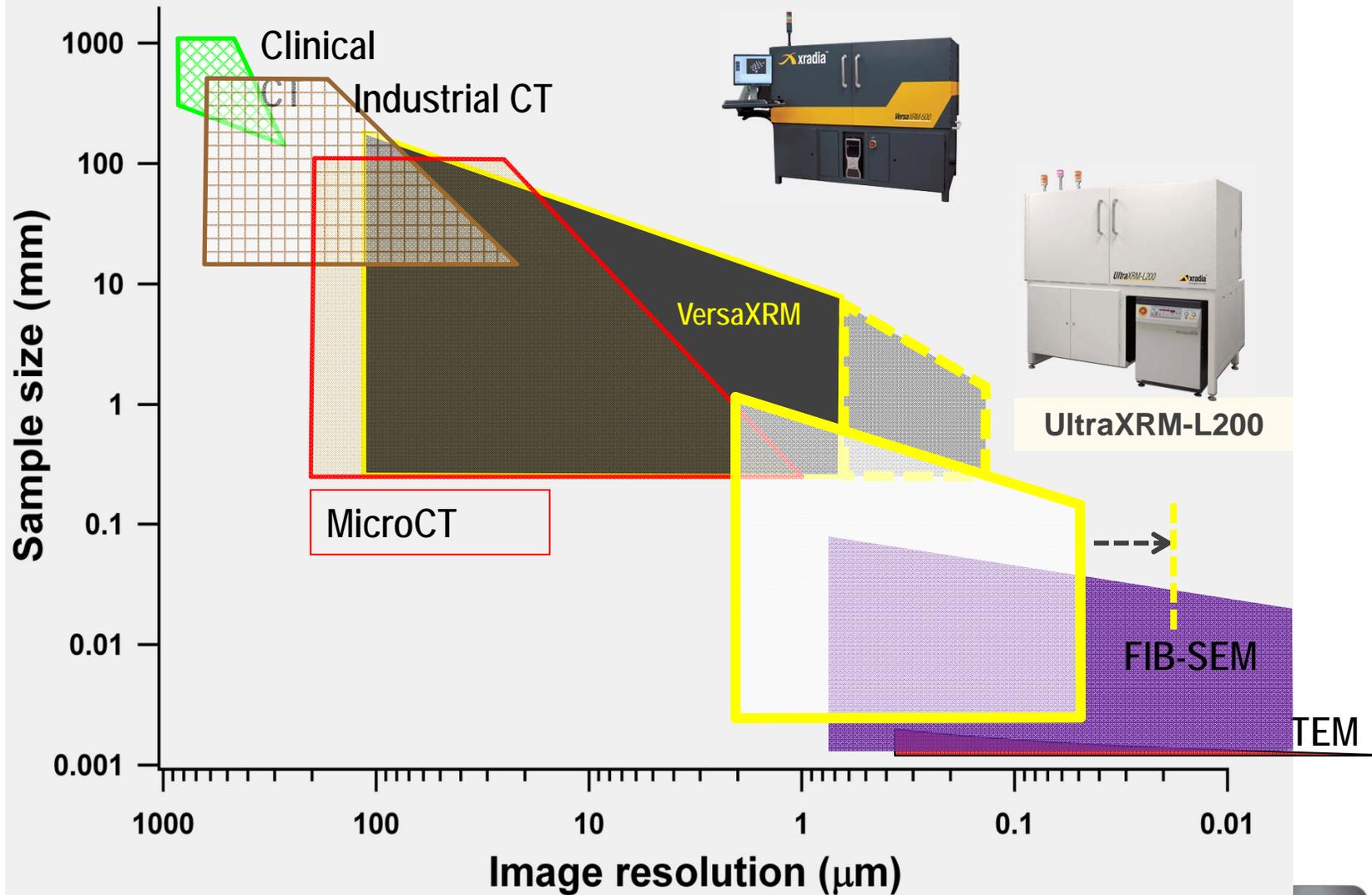


# Evolution of X-ray Imaging Techniques in Electronics

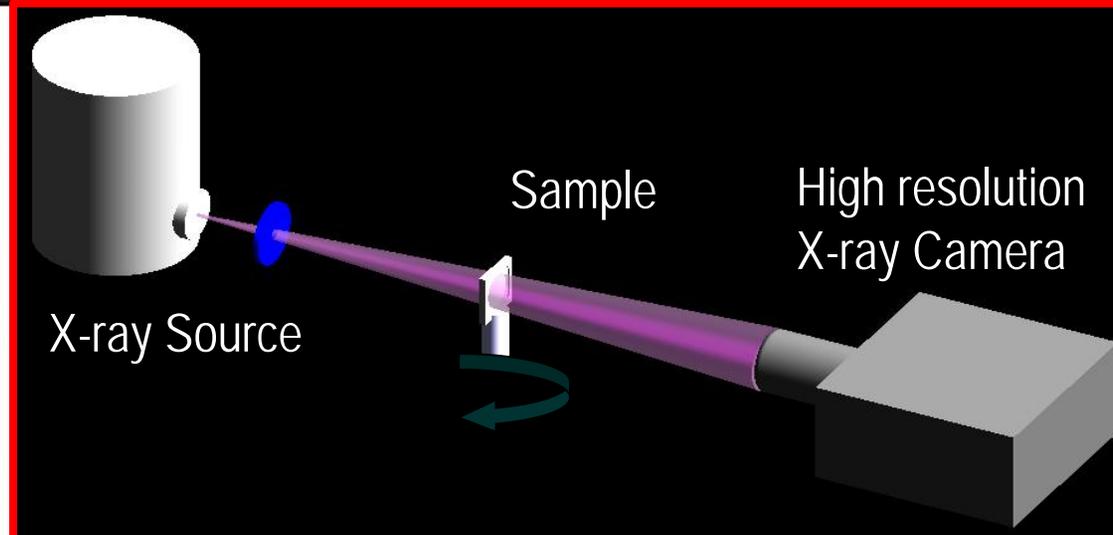


- ❑ Complexity of 3-D integration on IC and package level drives the need for non-destructive 3-D imaging
- ❑ Mostly for FA and process development
- ❑ Enabled by development of x-ray detector and optics technology

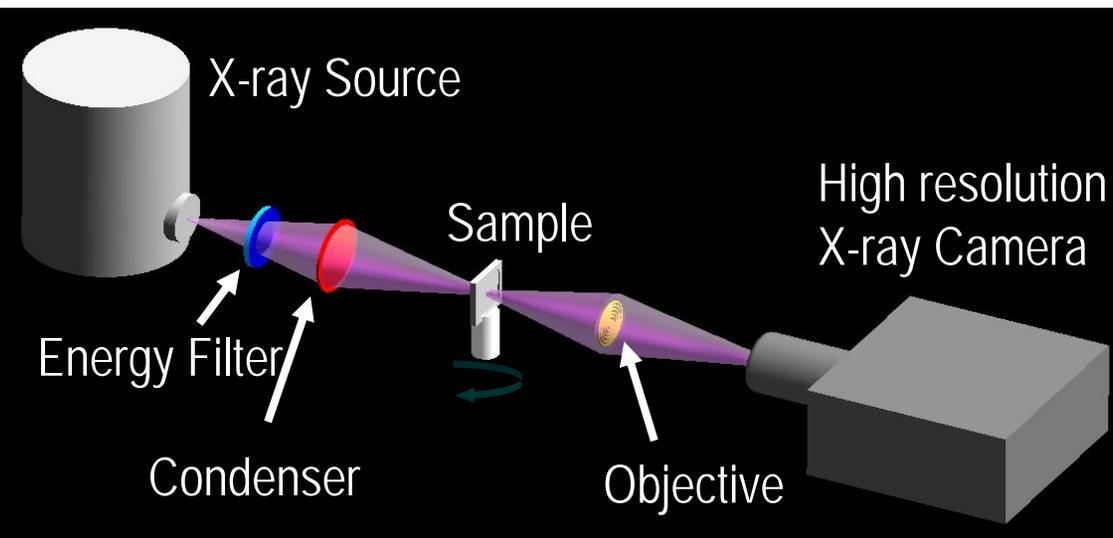
# Multi-scale 3-D Imaging



# 3-D X-ray Microscope Architectures



Point Projection Imaging  
"VersaXRM"  
0.7 $\mu$ m spatial resolution

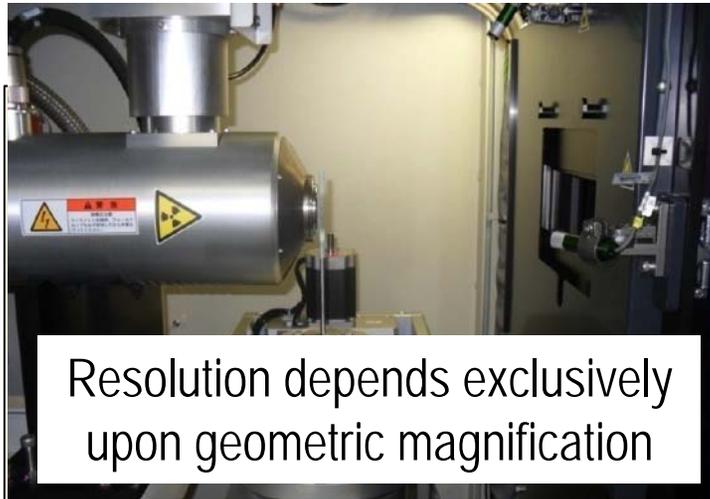


X-ray Lens Based Imaging  
"UltraXRM"  
50nm spatial resolution

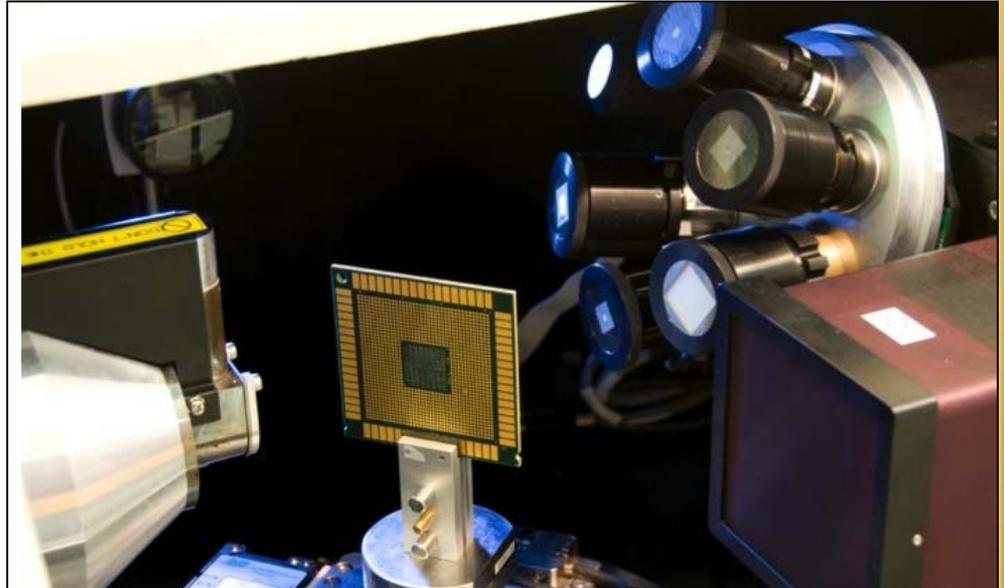


# Micro CT vs. 3D X-ray Microscopy

## Traditional Projection based Micro CT



## X-Ray Microscopy (XRM)



**Res**  Highest resolution limited to < 1mm samples

High resolution maintained for samples as large as 50 mm

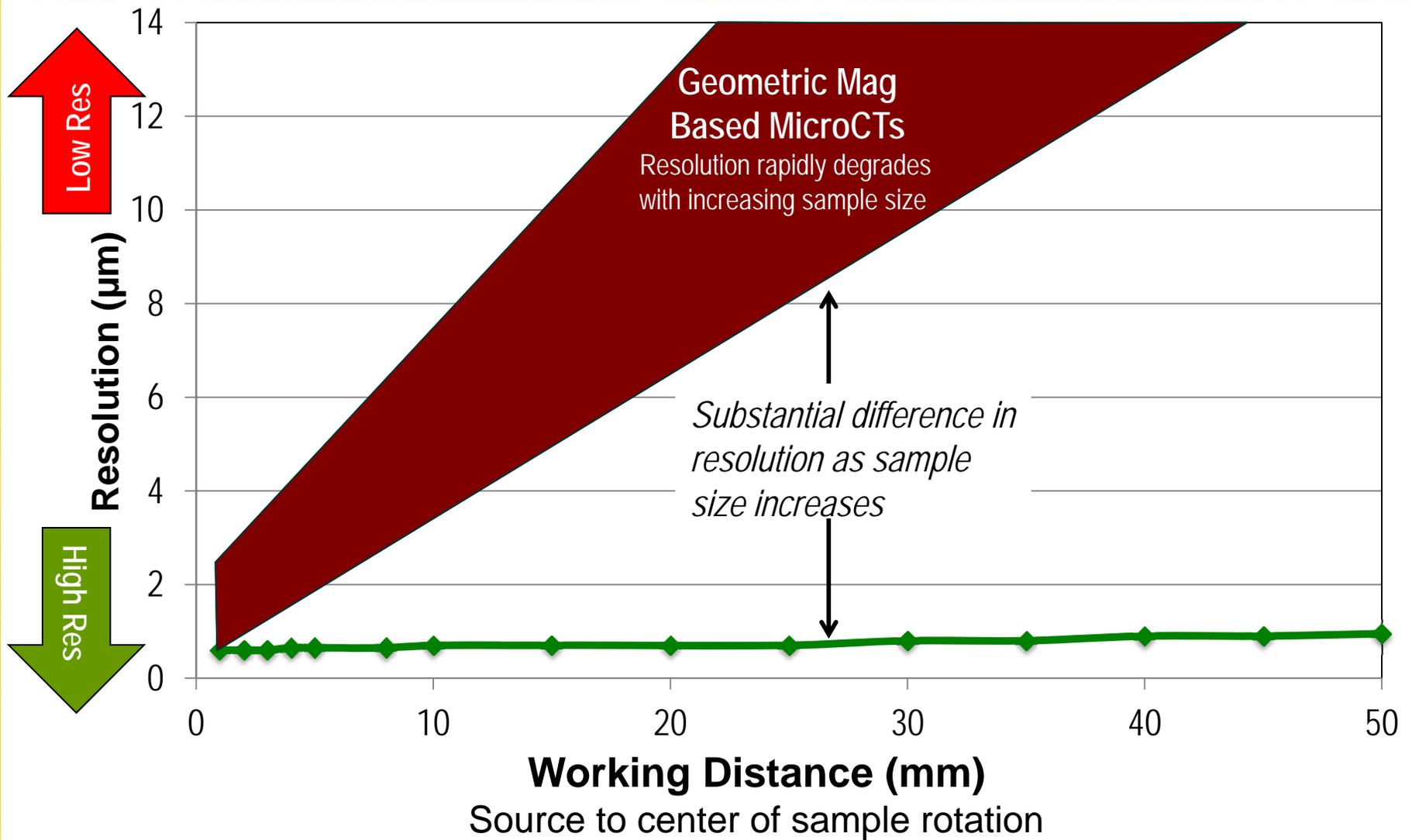
**Detector**  Large pixel size – no magnification

Optically magnified x-ray detector with sub-um resolution

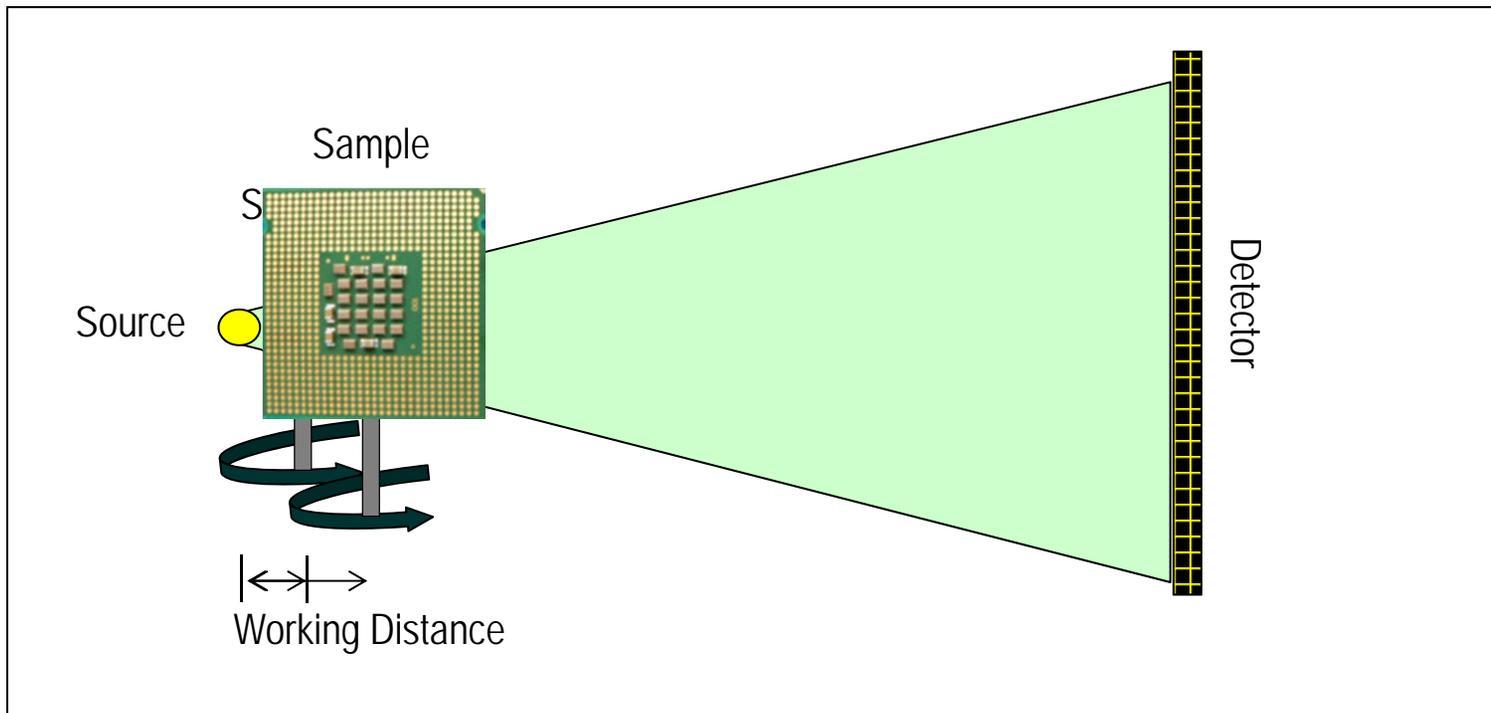
**Working Distance**  Res. Degrades linearly with sample size

Resolution is maintained, even for larger samples

# XRM Maintains High Resolution at Large Working Distances

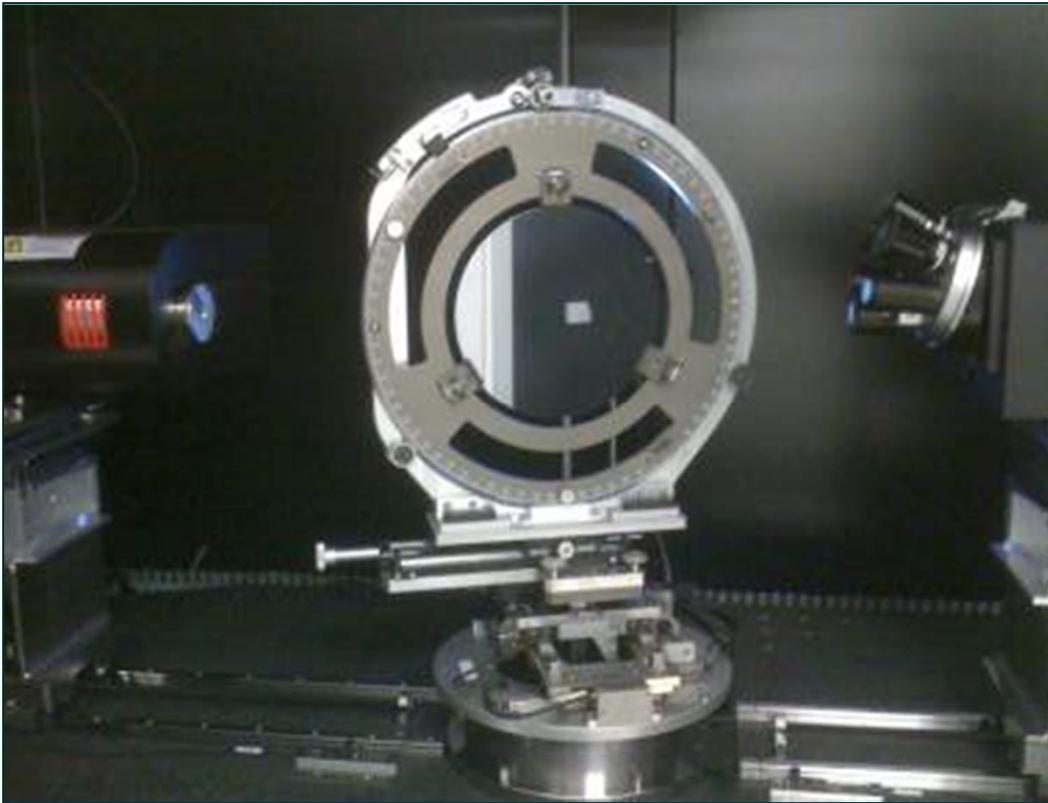


# Implication of Increased Working Distance



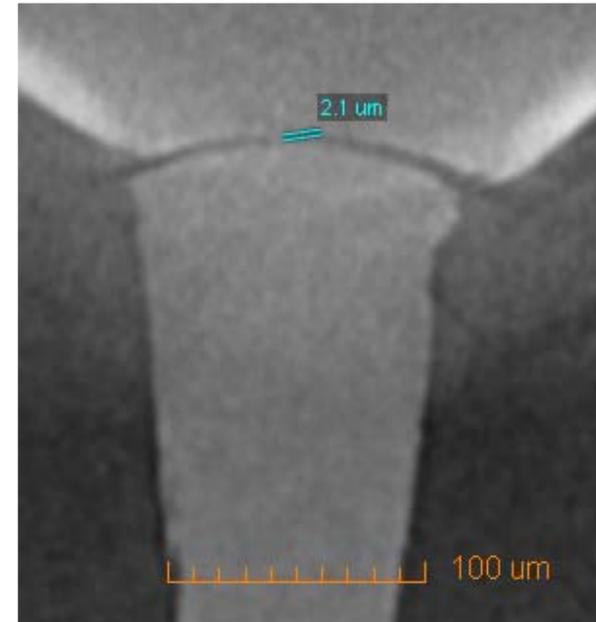
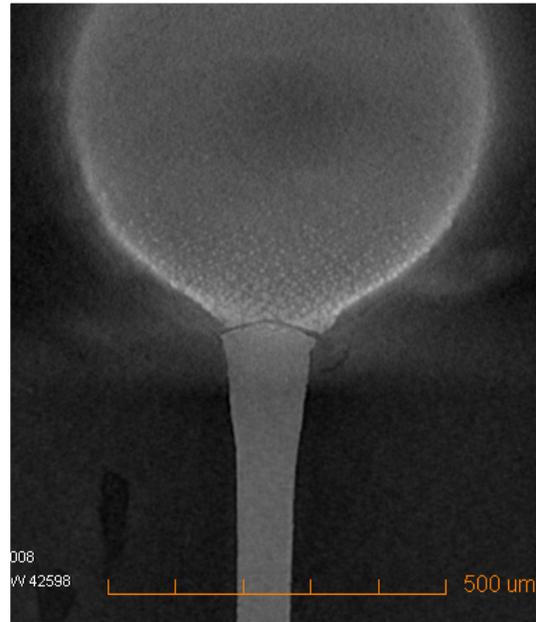
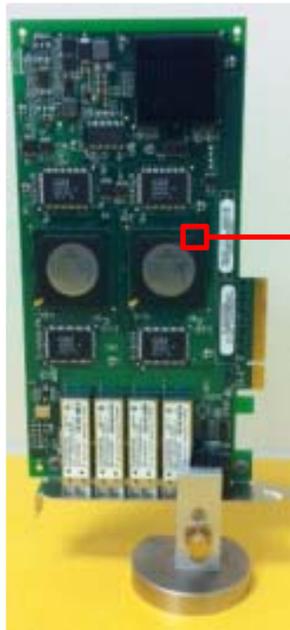
Working distance is pre-requisite to image larger samples relevant to electronics!

# Working Distance Enabler



Even whole wafers can be imaged → TSV development / FA

# Working Distance Enabler II



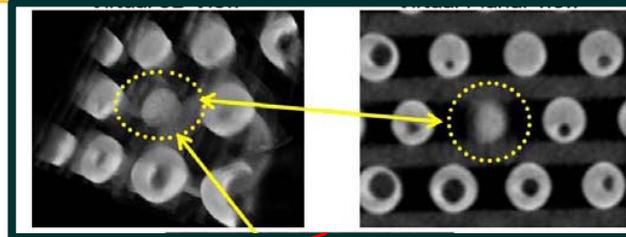
High resolution, even for large, completely intact samples

# What Does XRM Offer to Advanced Semiconductor Packaging?

Exceptionally:

- ✓ high resolution
- ✓ high contrast

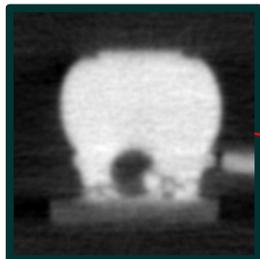
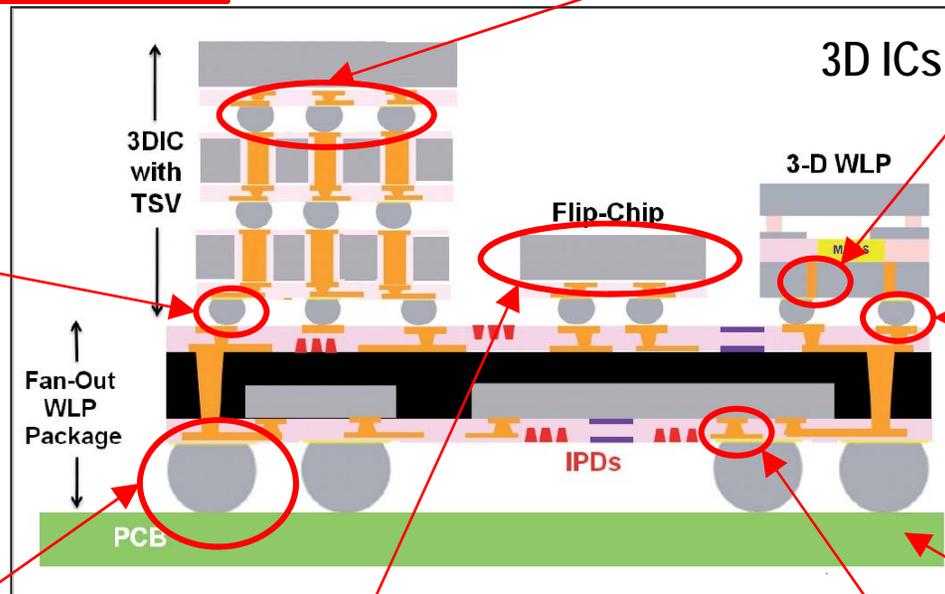
3D non-destructive imaging



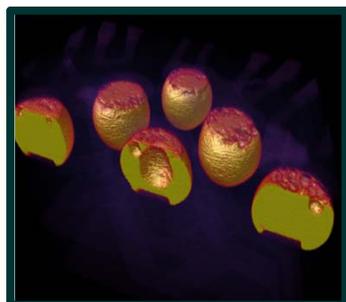
Solder Bump Non Wet



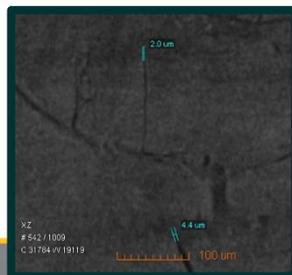
TSV Voids



Bump Voids



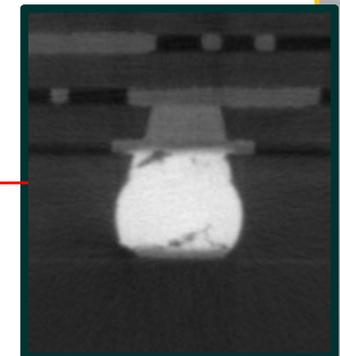
BGA Balls Defects



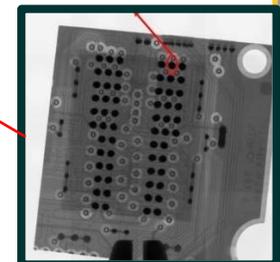
Si Die Cracks



Broken Vias

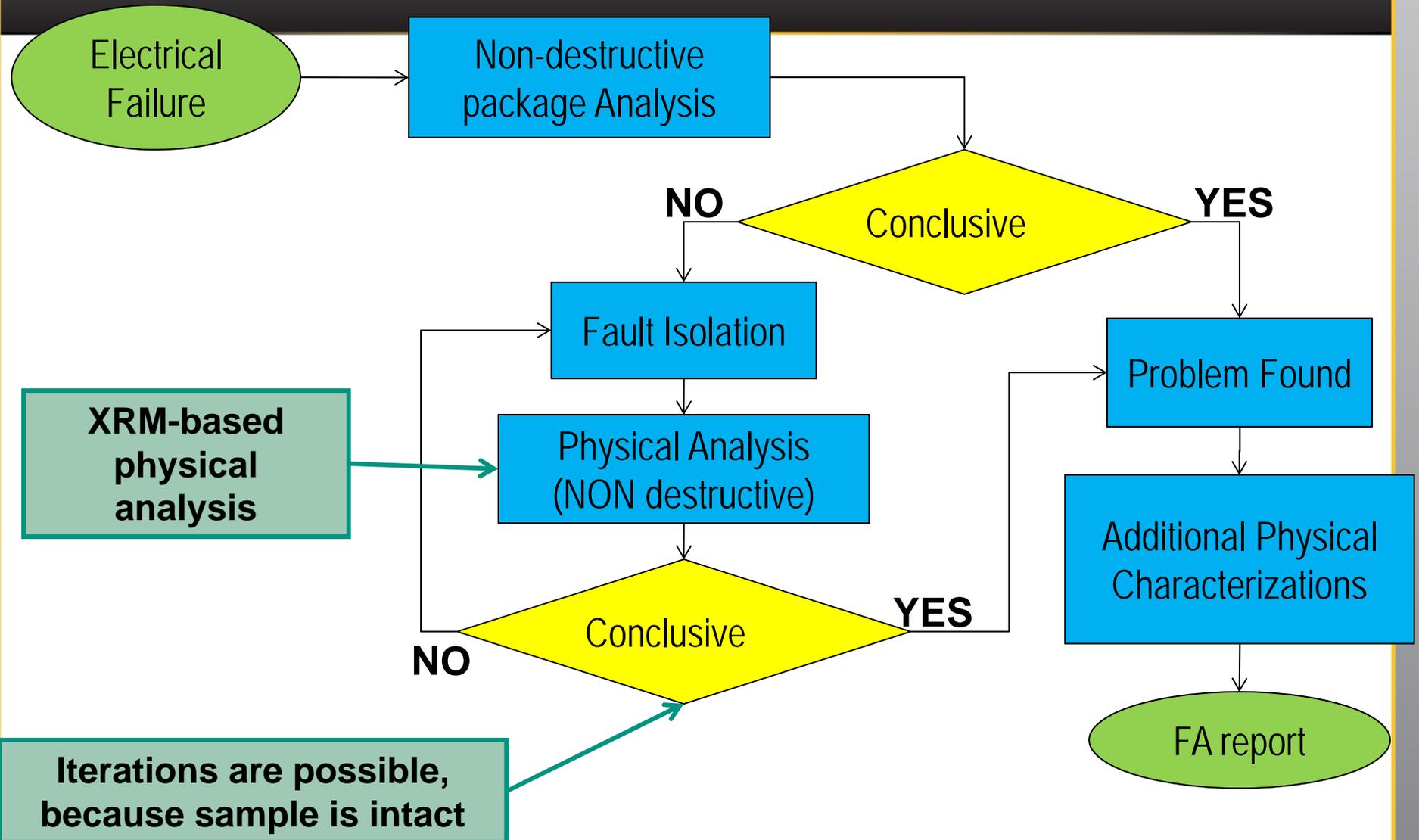


Bump Cracks



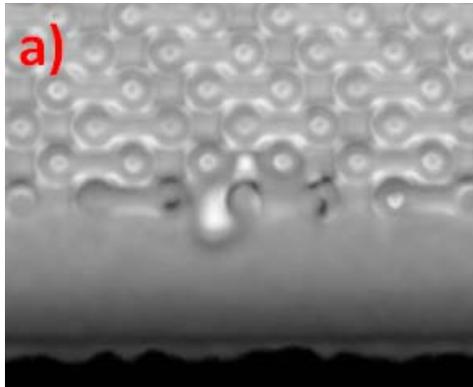
PCB & Substrate

# XRM-based FA flow (package failures)

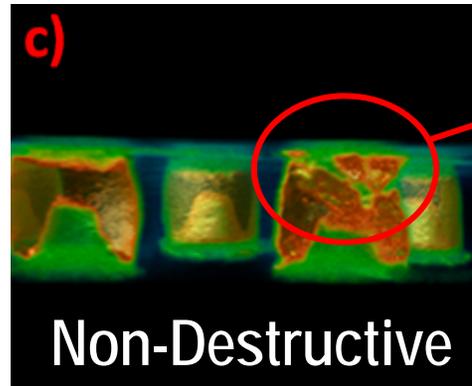
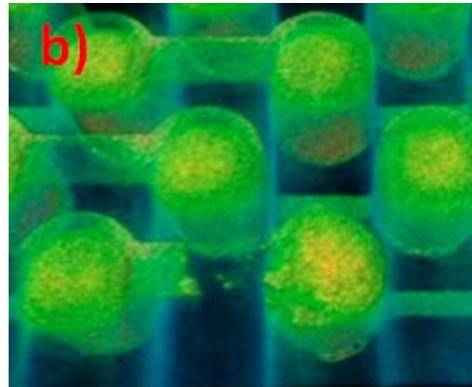


# Semi FA Example: Electro Migration Related Failure

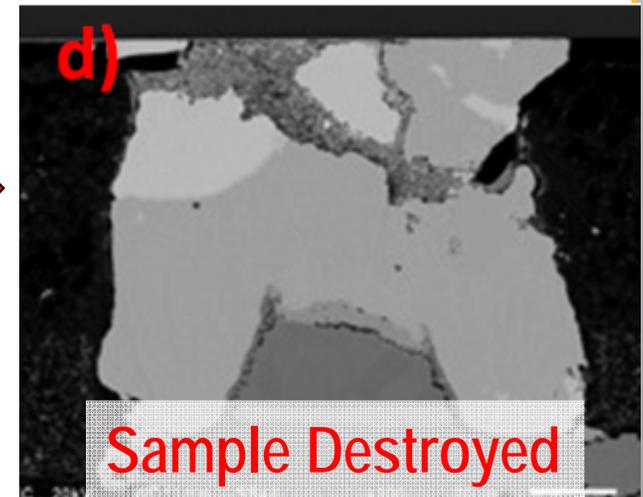
SAM



VersaXRM



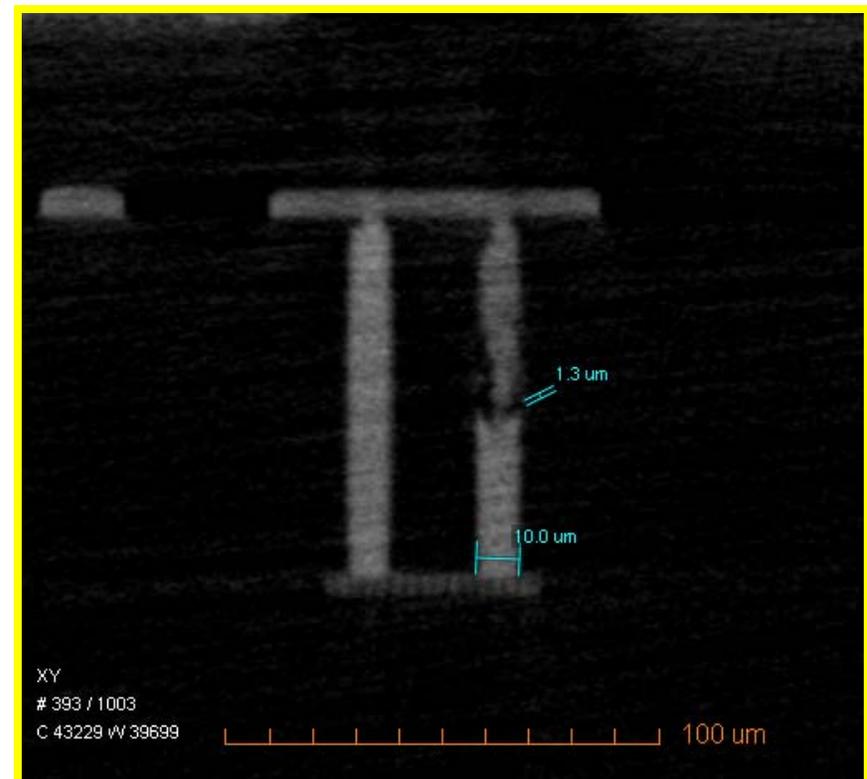
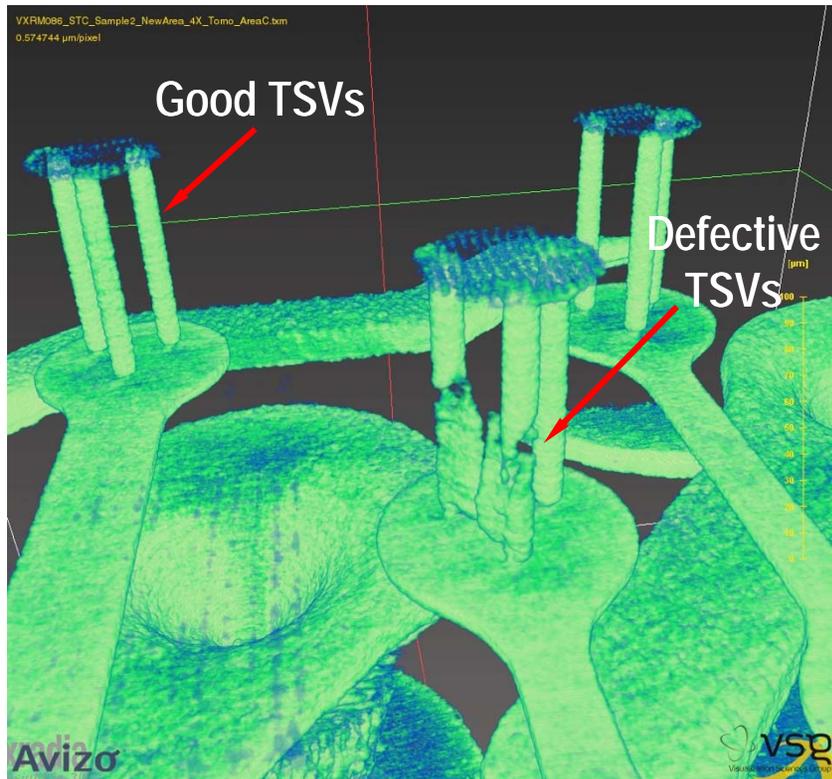
SEM X-section



**XRM for finding optimal location for physical cross section**

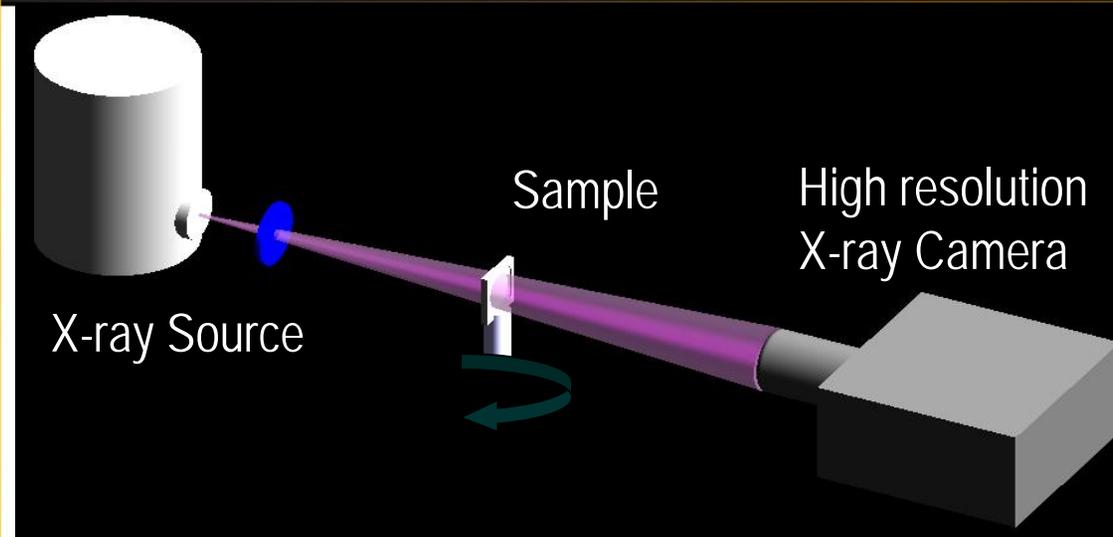
Source: "Applications of 3D X-Ray Microscopy for Advanced Package Development", K. Fahey, R. Estrada (Xradia), L. Mirkarimi, R. Katkar, D. Buckminster and M. Huynh, Tessera Technologies, Inc, IMAPS Long Beach 2011

# Non-Destructive High Res 3D for TSVs

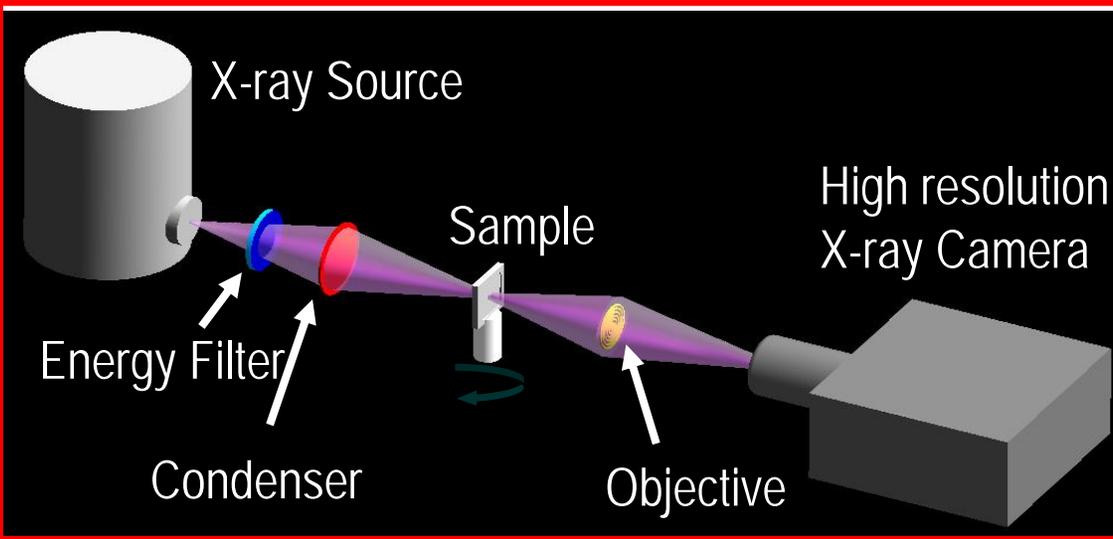


Ability to visualize TSV failure in intact package

# 3-D X-ray Microscope Architectures



Point Projection Imaging  
"VersaXRM"  
0.7 $\mu$ m spatial resolution



X-ray Lens Based Imaging  
"UltraXRM"  
50nm spatial resolution

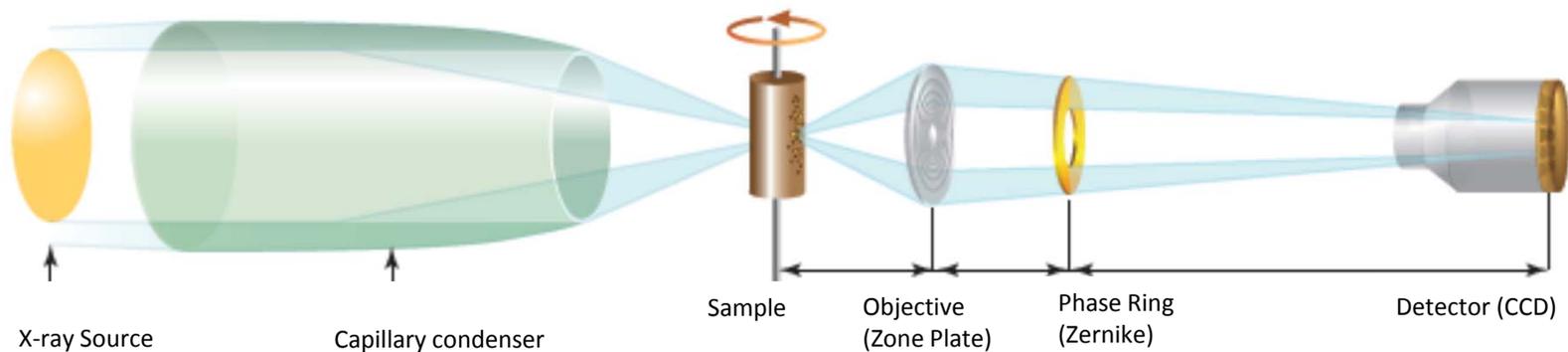
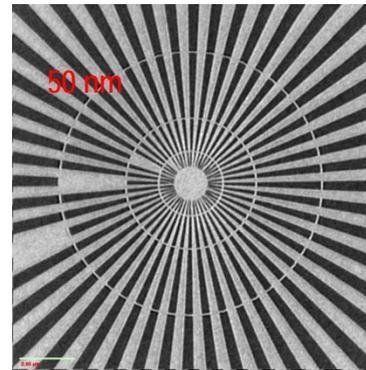


# UltraXRM: 3D X-ray Microscope using X-ray Optics

## 50 nm spatial (16 nm pixel) resolution

- High brightness x-ray source (8kV)
- High efficiency reflective condenser
- High-resolution objective zone plate
- Zernike phase contrast optics
- Precision tomography system (auto-tomo!)

Mode	Mag	2D Res	Field of View
Large Field of View	200X	150 nm	65 $\mu\text{m}$ x 65 $\mu\text{m}$
High Resolution	800X	50 nm	15 $\mu\text{m}$ x 15 $\mu\text{m}$



# Post-metallization TSV – UltraXRM

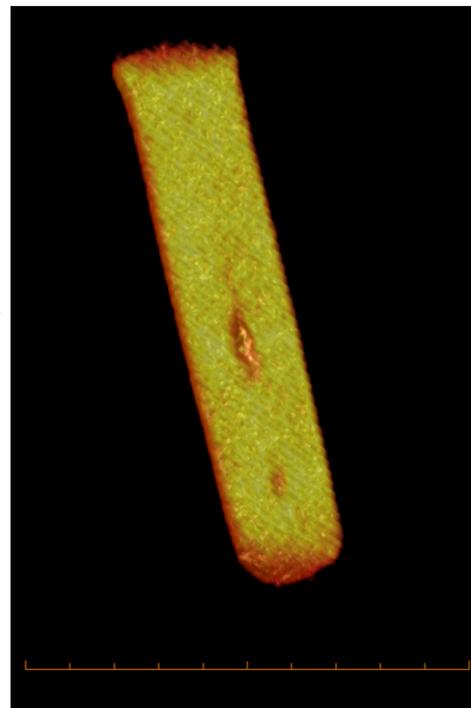


Cross Sectioning

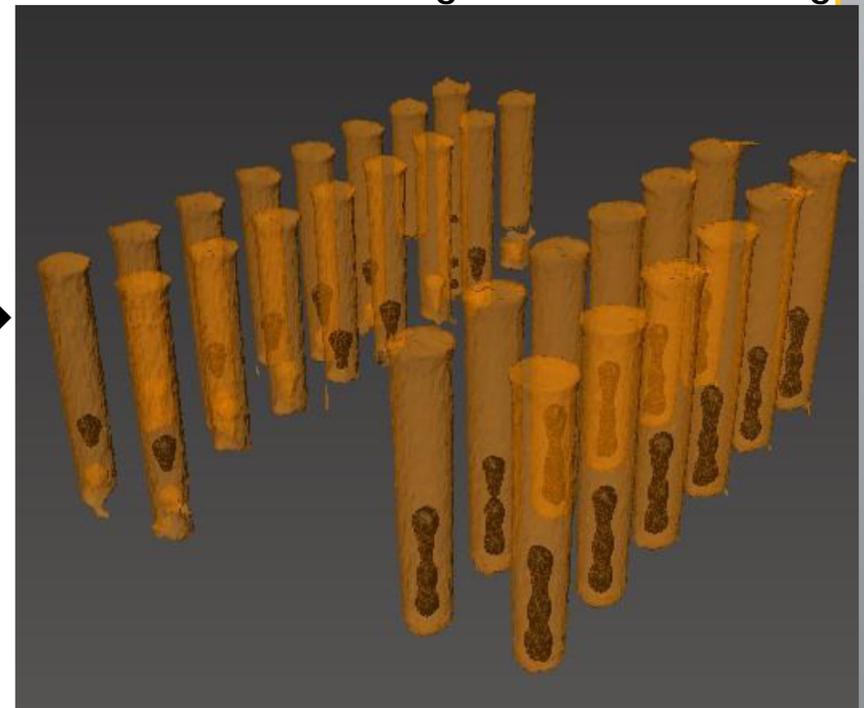
2D Virtual Cross Section



3D Isolated TSV



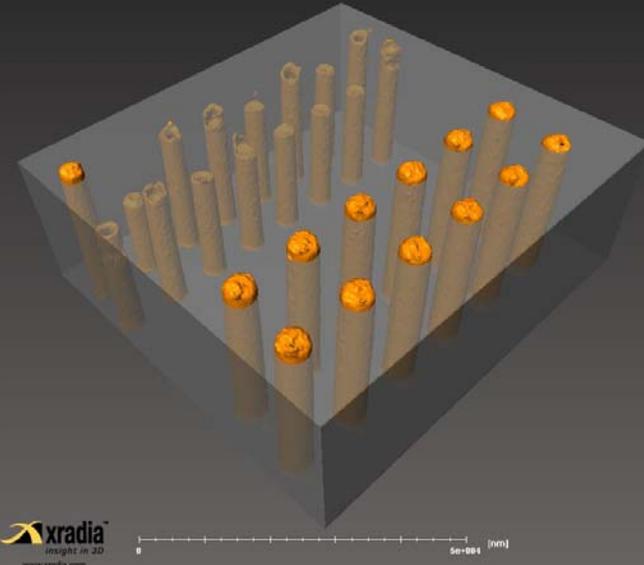
3D Rendered Large Field of View Image



3D interconnects: Applying X-ray microscopy as a void inspection technique for Through Silicon Vias, Lay Wai Kong, CNSE Albany/NY, US  
FRAUNHOFER WORKSHOP ON STRESS MANAGEMENT FOR 3D IC'S USING THROUGH SILICON VIAS Oct 20, 2010

# Ultra: TSV Metallization – Quantitative Analysis

Through-silicon vias: 150 nm resolution



Through-silicon vias: 150 nm resolution



From images, to information, to data

Remove Si



Segment Voids



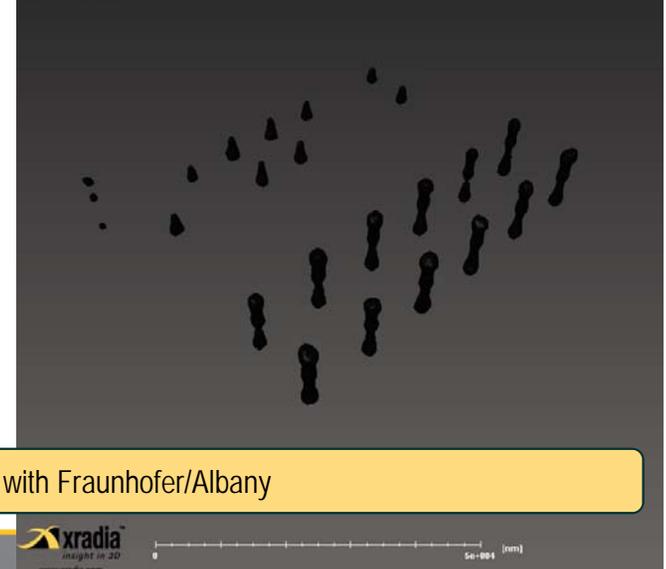
Remove Cu  
(voids only)



Through-silicon vias: 150 nm resolution



Through-silicon vias: 150 nm resolution



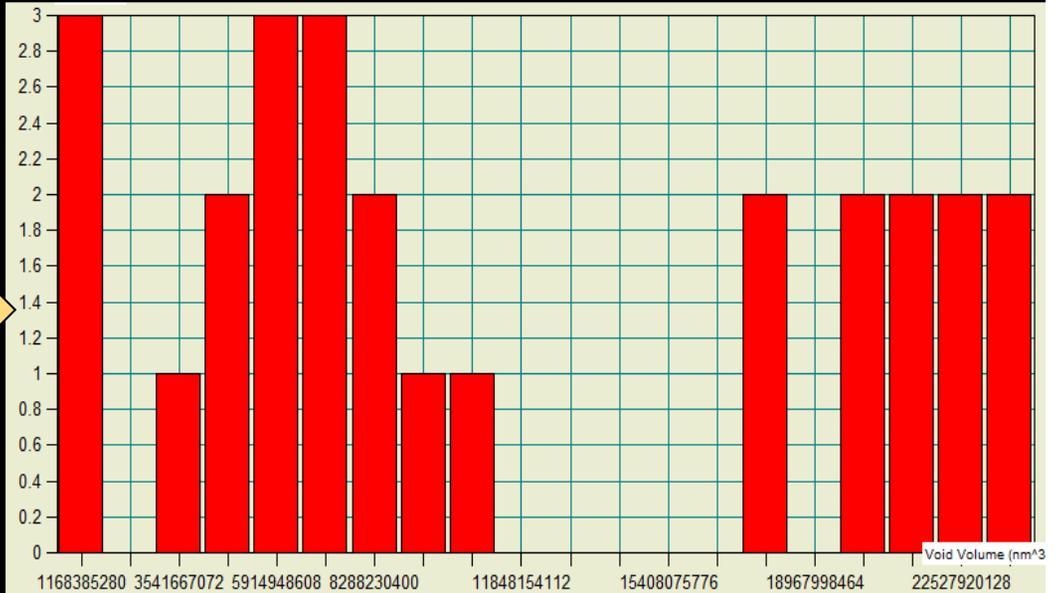
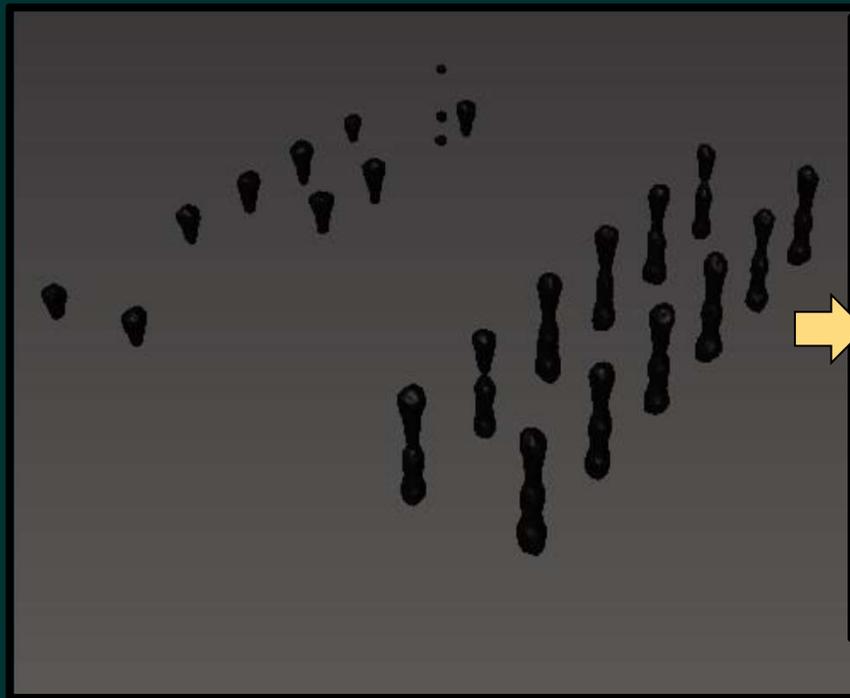
Collaboratoion with Fraunhofer/Albany

# Quantifying Void Space / Volume

UltraXRM-L200 results: Segmentation enables Void Space Analysis

3D Rendered, Segmented Voids

Distribution Analysis of Void Space (nm<sup>3</sup>)



Segmentation of 3-D data allows objective, quantitative analysis of complex structures

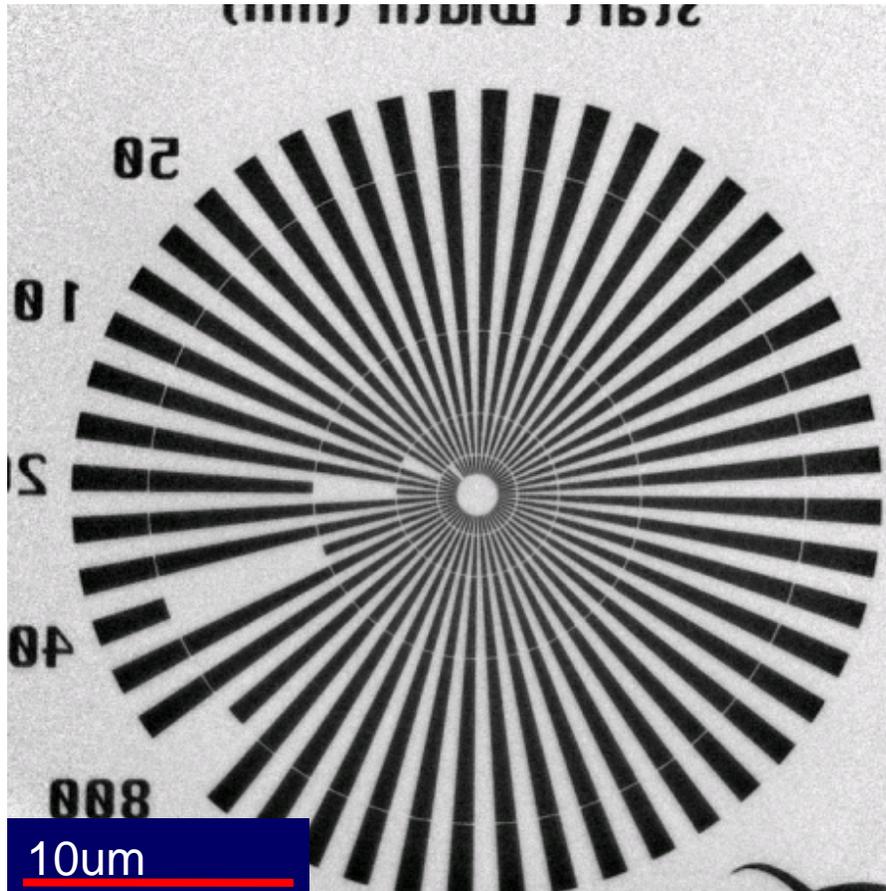
# Comparison with Other Imaging Modalities

	X ray UltraXRM	Optical	SEM	(S)TEM
Wavelength	0.1nm	100-1000	0.01	0.001-0.003
Spatial resolution	30 nm	200-300 nm	1-10 nm	0.1 nm
Contrast Mechanism	Absorption, Phase Contrast	Transmission, Reflectivity, Refractive Index, Labels	Secondary El., Backscattered El., EDS/WED	Electron Density, EELS, EDS, EBSD...
Max sample thickness	~50-500 $\mu\text{m}$	Optically transparent only	< 10 nm typical	<<200 nm
Vacuum requirement	No	No	Yes	Yes

- Penetration of x-rays major advantage to nondestructively image a 3-Dimensional volume
- Resolution currently limited by optics (not physics)
  - single digit nm resolution should be reached for 3-D x-ray imaging eventually (not aberration limited like EM)

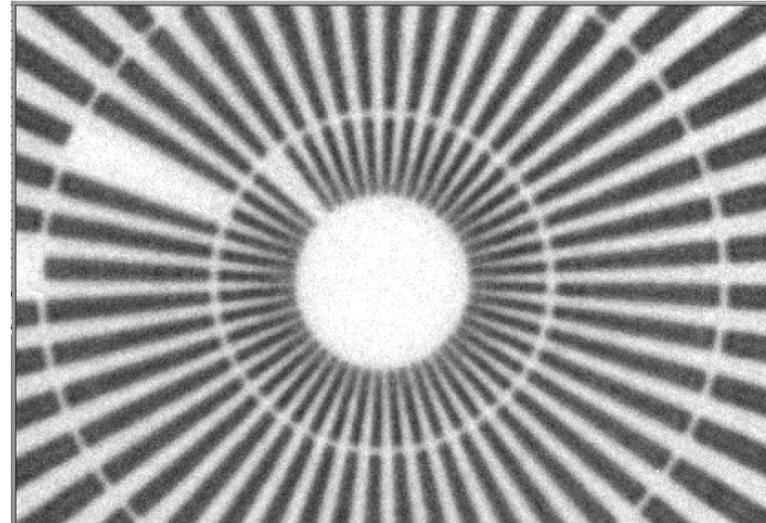


# Resolution Better Than 50nm – FOV 32 $\mu$ m



Field of View > 32x32 $\mu$ m  
2k x 2k (1s image time)

Same image zoomed in.  
50nm smallest features

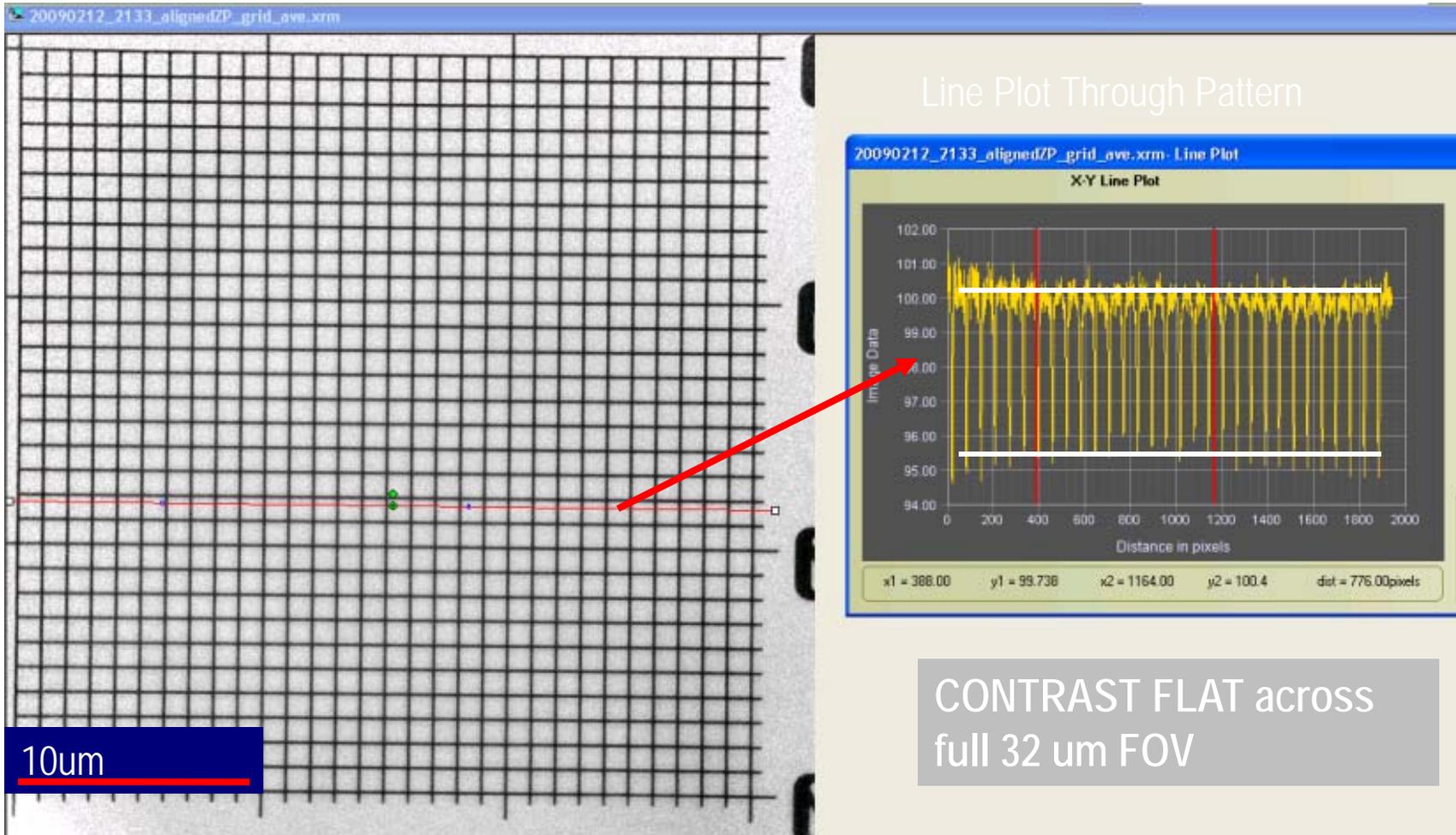


Resolution 30nm

Stanford Synchrotron SSRL  
Beamline 6.2 Xradia UltraXRM



# Contrast Uniformity

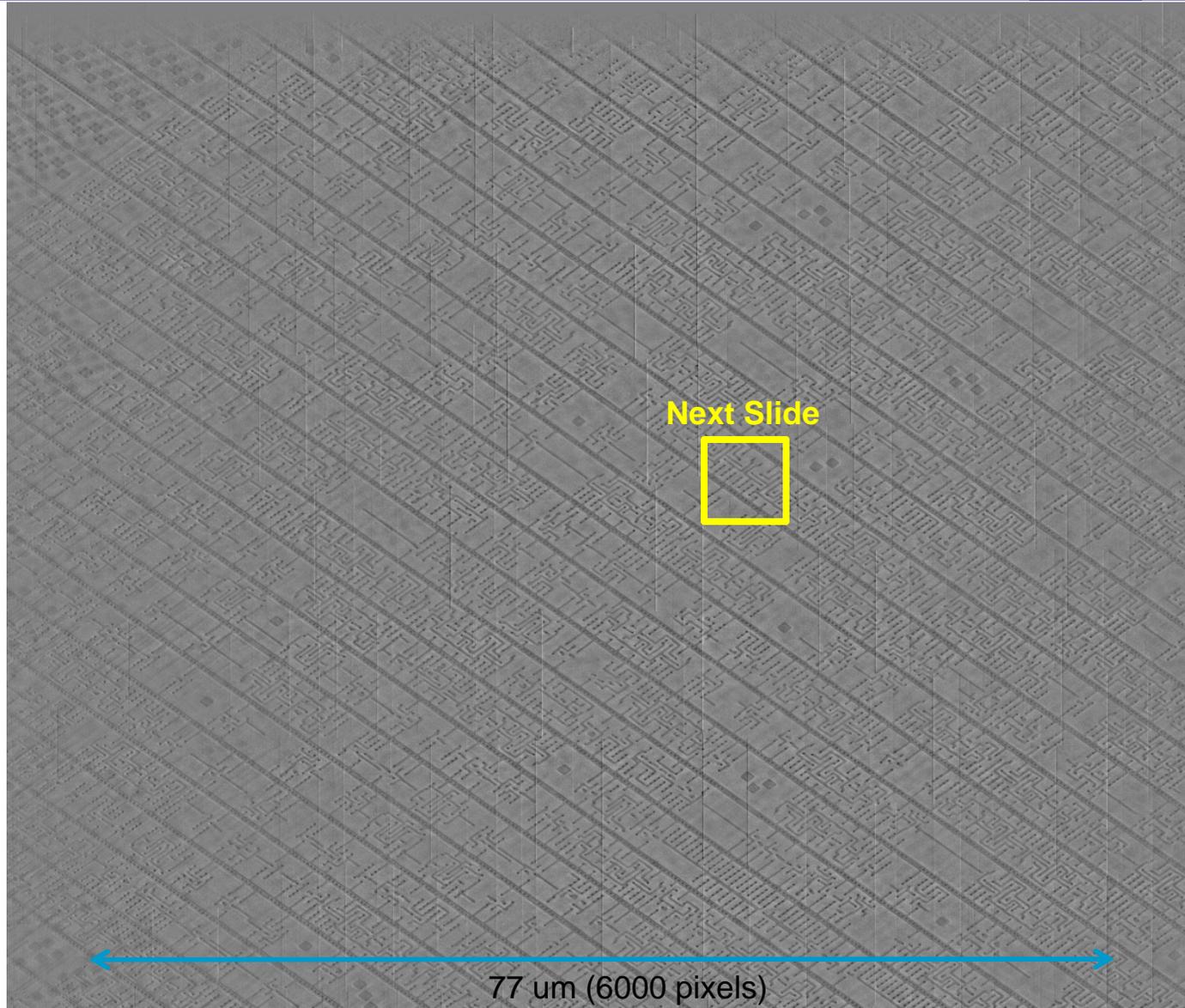




# Automated Tomography of 70 um x 70 um M1 Slice – Still Image



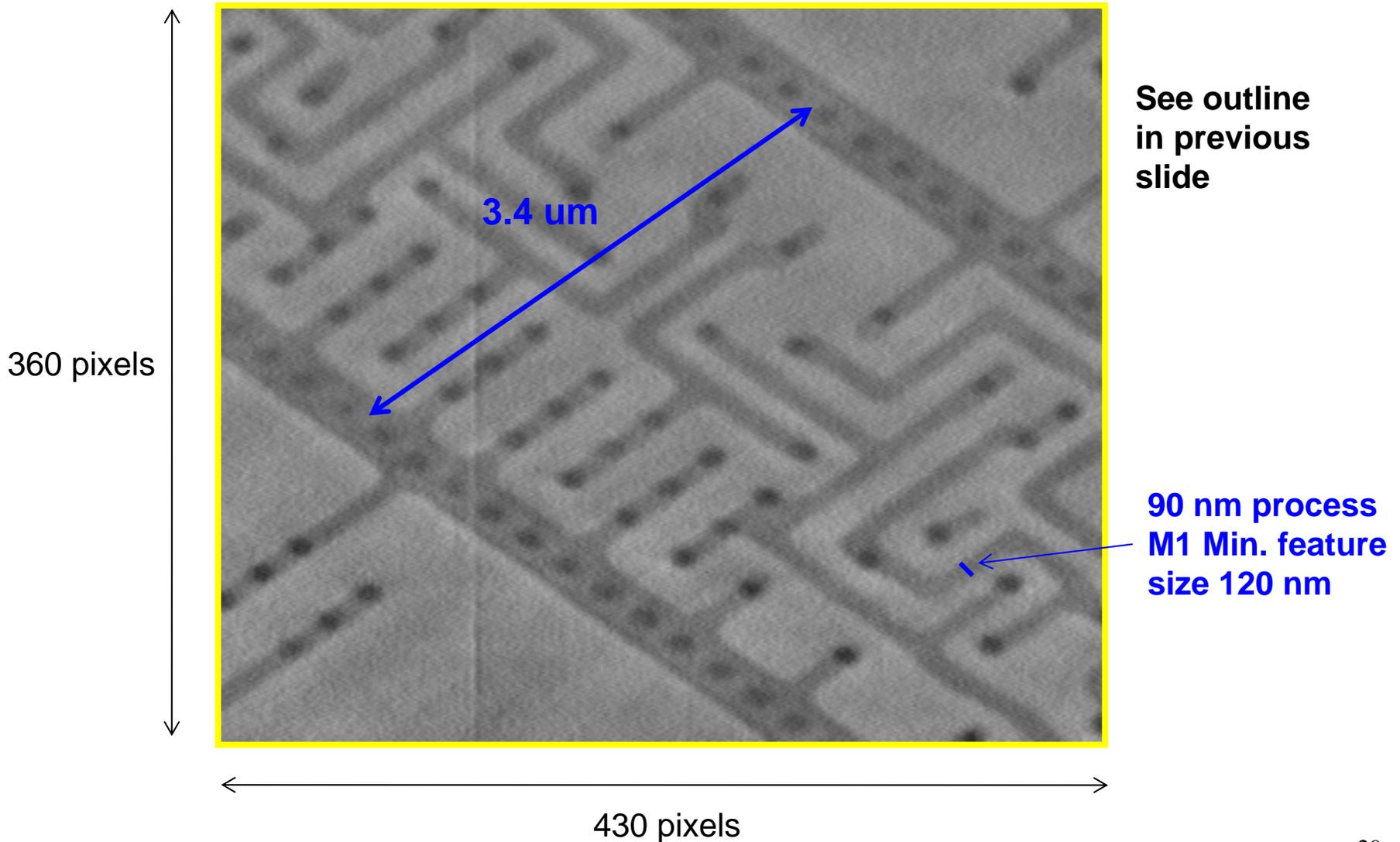
77 um  
(5100 pixels)



77 um (6000 pixels)



# Automated Tomography Closeup of Virtual Delaying M1



# Conclusion - What Makes XRM Unique?

## *Penetration, Large Working Distance at Highest Resolution*

- ❑ X-ray microscopy (XRM) can bridge the gap between NDT and high resolution EM / FIB
- ❑ Address challenges of large, complex 3-D electronic packages
  - High Resolution
  - High Contrast
- ❑ **4D characterization** (before/after stress test or cycling)
- ❑ TSV imaging (UltraXRM)
- ❑ Design verification for TRUST on ICs (UltraXRM)

*Not a Substitute for EM/FIB Microscopy for IC FEOL Imaging or smallest BEOL structures*